

SEMICONDUCTOR TM

## KSC2690/2690A

# **Audio Frequency** High Frequency Power Amplifier Complement to KSA1220/KSA1220A



### **NPN Epitaxial Silicon Transistor**

Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage		
	: KSC2690	120	V
	: KSC2690A	160	V
V <sub>CEO</sub>	Collector- Emitter Voltage		
020	: KSC2690	120	V
	: KSC2690A	160	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current (DC)	1.2	А
I <sub>CP</sub>	*Collector Current (Pulse)	2.5	А
I <sub>B</sub>	Base Current(DC)	0.3	А
P <sub>C</sub>	Collector Dissipation (T <sub>a</sub> =25°C)	1.2	W
P <sub>C</sub> P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	20	W
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

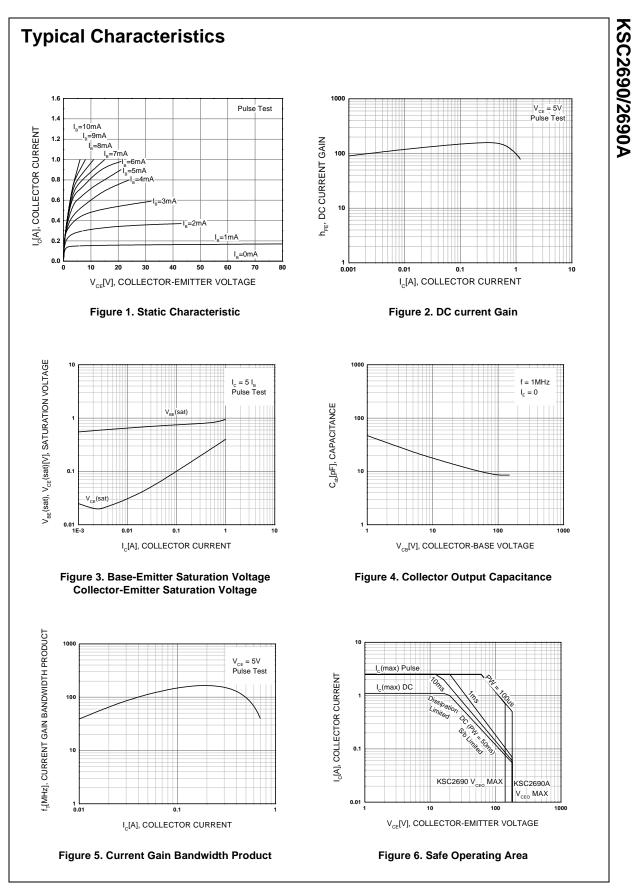
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> = 120V, I <sub>E</sub> = 0			1	μΑ
I <sub>EBO</sub>	Emitter Cut-off Current	V <sub>EB</sub> = 3V, I <sub>C</sub> = 0			1	μΑ
h <sub>FE1</sub>	* DC Current Gain	$V_{CE} = 5V, I_{C} = 5mA$	35	105		
h <sub>FE2</sub>		$V_{CE} = 5V, I_{C} = 0.3A$	60	140	320	
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage	I <sub>C</sub> = 1A, I <sub>B</sub> = 0.2A		0.4	0.7	V
V <sub>BE</sub> (sat)	* Base-Emitter Saturation Voltage	I <sub>C</sub> = 1A, I <sub>B</sub> = 0.2A		1	1.3	V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 5V, I_{C} = 0.2A$		155		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f = 1MHz		19		pF

\* Pulse Test: PW≤350µs, Duty Cycle≤2% Pulsed

### h<sub>FE</sub> Classificntion

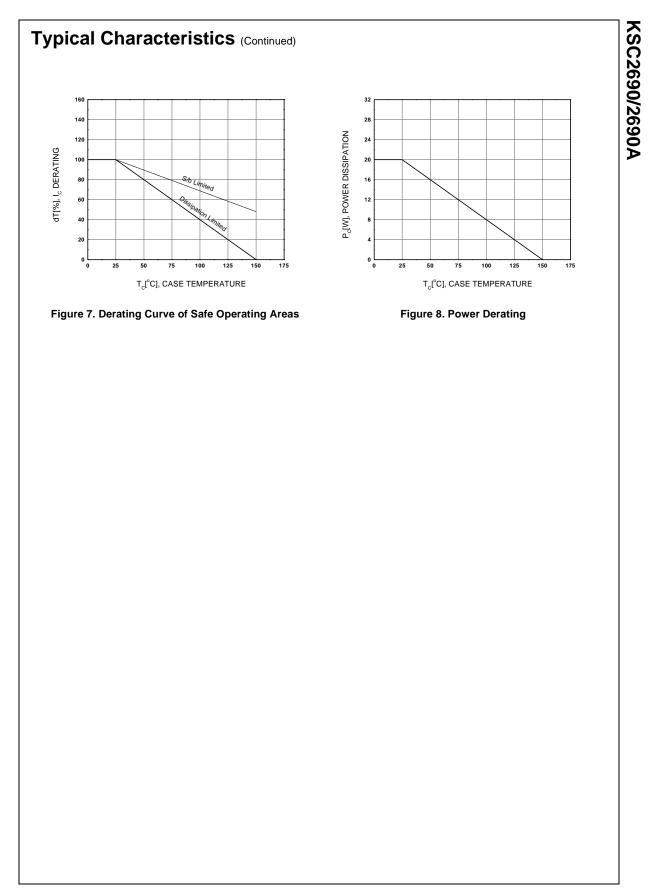
Classification	R	0	Y
h <sub>FE2</sub>	60 ~ 120	100 ~ 200	160 ~ 320

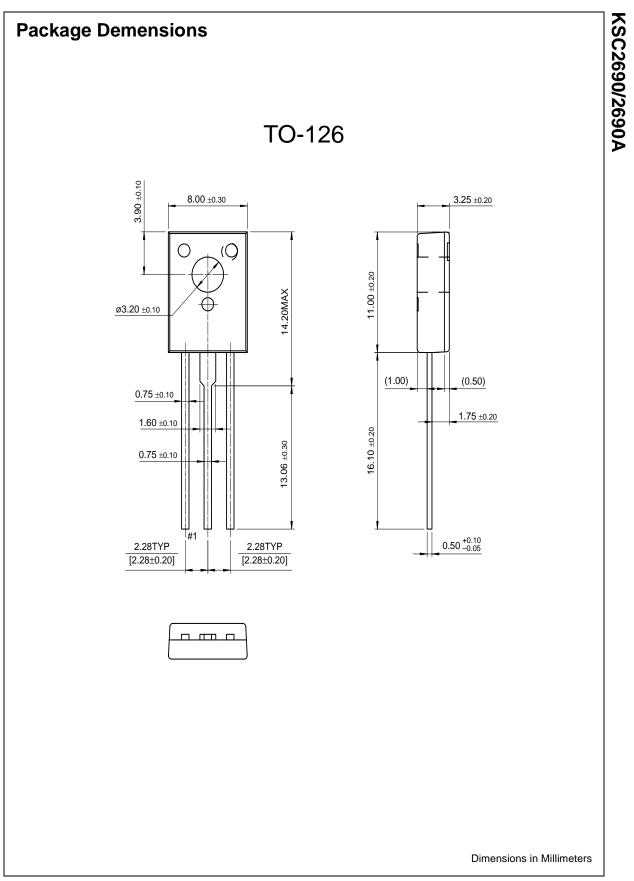
Rev. A, February 2000



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